



Is Now Part of



ON Semiconductor®

To learn more about ON Semiconductor, please visit our website at
www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.



ON Semiconductor®

March 2017

FNB51060T1

Motion SPM® 55 Series

Features

- UL Certified No. E209204 (UL1557)
- 600 V - 10 A 3-Phase IGBT Inverter Including Control IC for Gate Drive and Protections
- Low-Loss, Short-Circuit Rated IGBTs
- Separate Open-Emitter Pins from Low-Side IGBTs for Three-Phase Current Sensing
- Active-HIGH interface, works with 3.3 / 5 V Logic, Schmitt-trigger Input
- HVIC for Gate Driving, Under-Voltage and Short-Circuit Current Protection
- Fault Output for Under-Voltage and Short-Circuit Current Protection
- Inter-Lock Function to Prevent Short-Circuit
- Shut-Down Input
- HVIC Temperature-Sensing Built-In for Temperature Monitoring
- Optimized for 15 kHz Switching Frequency
- Isolation Rating: 1500 V_{rms} / min.

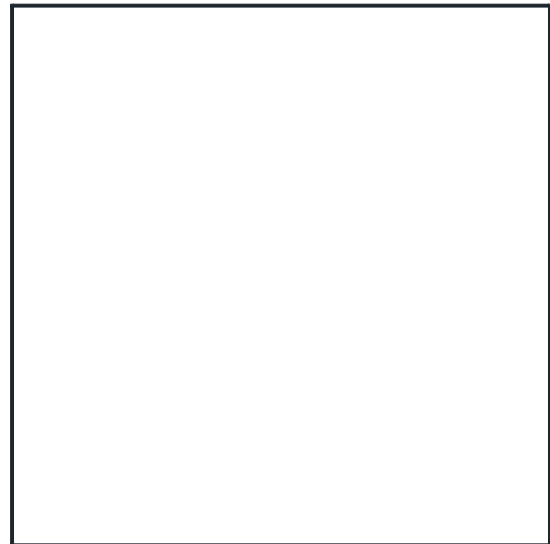
Applications

- Motion Control - Home Appliance / Industrial Motor

Related Resources

General Description

FNB51060T1 is a Motion SPM 55 module providing a fully-featured, high-performance inverter output stage for AC Induction, BLDC, and PMSM motors. These modules integrate optimized gate drive of the built-in IGBTs to minimize EMI and losses, while also providing multiple on-module protection features including under-voltage lockouts, inter-lock function, over-current shutdown, thermal monitoring of drive IC, and fault reporting. The built-in, high-speed HVIC requires only a single supply voltage and translates the incoming logic-level gate inputs to the high-voltage, high-current drive signals required to properly drive the module's robust short-circuit-rated IGBTs. Separate negative IGBT terminals are available for each phase to support the widest variety of control algorithms.



**Figure 1. 3D Package Drawing
(Click to Activate 3D Content)**

Package Marking and Ordering Information

| Device | Device Marking | Package | Packing Type | Quantity |
|------------|----------------|-----------|--------------|----------|
| FNB51060T1 | FNB51060T1 | SPMFA-B20 | RAIL | 13 |

Integrated Power Functions

- 600 V - 10 A IGBT inverter for three phase DC / AC power conversion (Please refer to Figure 3)

Integrated Drive, Protection and System Control Functions

- For inverter high-side IGBTs: gate drive circuit, high-voltage isolated high-speed level shifting control circuit Under-Voltage Lock-Out (UVLO) protection
- For inverter low-side IGBTs: gate drive circuit, Short-Circuit Protection (SCP) control supply circuit Under-Voltage Lock-Out (UVLO) protection
- Fault signaling: corresponding to UVLO (low-side supply) and SC faults
- Input interface: High-active interface, works with 3.3 / 5 V logic, Schmitt trigger input

Pin Configuration

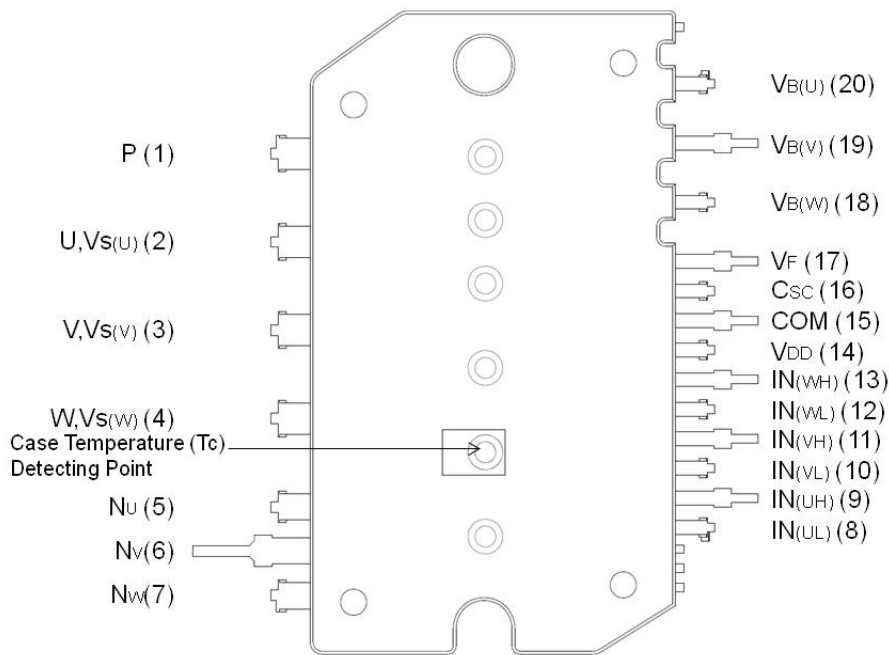


Figure 2. Top View

Pin Descriptions

| Pin Number | Pin Name | Pin Description |
|------------|-------------|---|
| 1 | P | Positive DC-Link Input |
| 2 | U, $V_S(U)$ | Output for U Phase |
| 3 | V, $V_S(V)$ | Output for V Phase |
| 4 | W, $V_S(W)$ | Output for W Phase |
| 5 | N_U | Negative DC-Link Input for U Phase |
| 6 | N_V | Negative DC-Link Input for V Phase |
| 7 | N_W | Negative DC-Link Input for W Phase |
| 8 | $IN_{(UL)}$ | Signal Input for Low-Side U Phase |
| 9 | $IN_{(UH)}$ | Signal Input for High-Side U Phase |
| 10 | $IN_{(VL)}$ | Signal Input for Low-Side V Phase |
| 11 | $IN_{(VH)}$ | Signal Input for High-Side V Phase |
| 12 | $IN_{(WL)}$ | Signal Input for Low-Side W Phase |
| 13 | $IN_{(WH)}$ | Signal Input for High-Side W Phase |
| 14 | V_{DD} | Common Bias Voltage for IC and IGBTs Driving |
| 15 | COM | Common Supply Ground |
| 16 | C_{SC} | Capacitor (Low-Pass Filter) for Short-circuit Current Detection Input |
| 17 | V_F | Fault Output, Shut-Down Input, Temperature Output of Drive IC |
| 18 | $V_{B(W)}$ | High-Side Bias Voltage for W-Phase IGBT Driving |
| 19 | $V_{B(V)}$ | High-Side Bias Voltage for V-Phase IGBT Driving |
| 20 | $V_{B(U)}$ | High-Side Bias Voltage for U-Phase IGBT Driving |

Internal Equivalent Circuit and Input/Output Pins

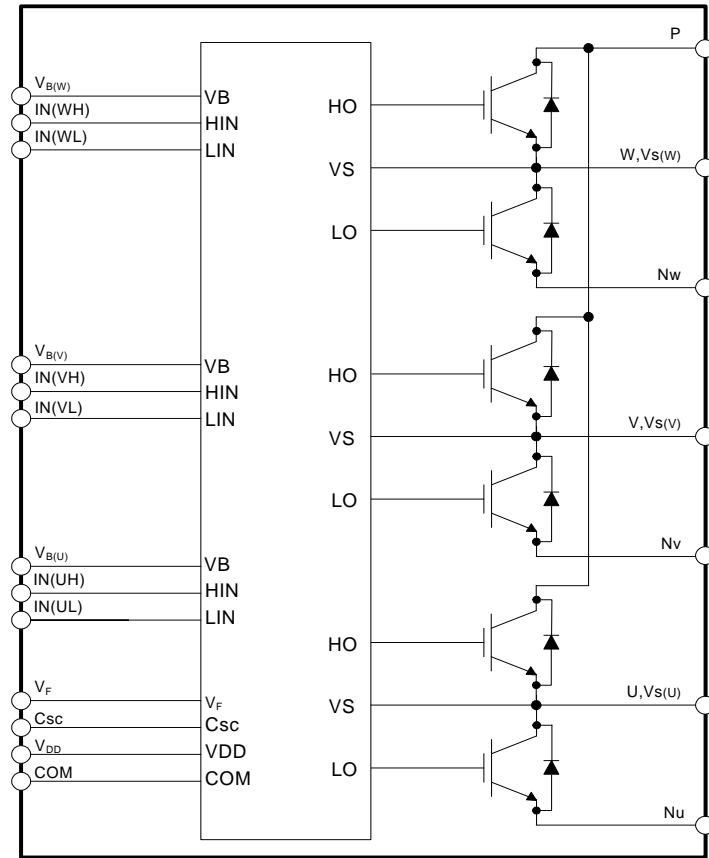


Figure 3. Internal Block Diagram

Note:

1. Inverter high-side is composed of three IGBTs, freewheeling diodes, and one control IC for each IGBT.
2. Inverter low-side is composed of three IGBTs, freewheeling diodes, and one control IC for each IGBT. It has gate drive and protection functions.
3. Single drive IC has gate driver for six IGBTs and protection functions.
4. Inverter power side is composed of four inverter DC-link input terminals and three inverter output terminals.

Absolute Maximum Ratings ($T_J = 25^\circ\text{C}$, unless otherwise specified.)

Inverter Part

| Symbol | Parameter | Conditions | Rating | Unit |
|------------------------|------------------------------------|---|-----------|------------------|
| V_{PN} | Supply Voltage | Applied between P - N_U , N_V , N_W | 450 | V |
| $V_{PN(\text{Surge})}$ | Supply Voltage (Surge) | Applied between P - N_U , N_V , N_W | 500 | V |
| V_{CES} | Collector - Emitter Voltage | | 600 | V |
| $\pm I_C$ | Each IGBT Collector Current | $T_C = 25^\circ\text{C}$, $T_J < 150^\circ\text{C}$ | 10 | A |
| $\pm I_{CP}$ | Each IGBT Collector Current (Peak) | $T_C = 25^\circ\text{C}$, $T_J < 150^\circ\text{C}$, Under 1 ms Pulse Width | 20 | A |
| P_C | Collector Dissipation | $T_C = 25^\circ\text{C}$ per Chip | 21 | W |
| T_J | Operating Junction Temperature | (Note 5) | -40 ~ 150 | $^\circ\text{C}$ |

Note:

5. The maximum junction temperature rating of the power chips integrated within the Motion SPM® 55 product is 150°C .

Control Part

| Symbol | Parameter | Conditions | Rating | Unit |
|----------|--------------------------------|---|-----------------------|------|
| V_{DD} | Control Supply Voltage | Applied between V_{DD} - COM | 20 | V |
| V_{BS} | High-Side Control Bias Voltage | Applied between $V_{B(U)}$ - $V_{S(U)}$, $V_{B(V)}$ - $V_{S(V)}$, $V_{B(W)}$ - $V_{S(W)}$ | 20 | V |
| V_{IN} | Input Signal Voltage | Applied between $IN_{(UH)}$, $IN_{(VH)}$, $IN_{(WH)}$, $IN_{(UL)}$, $IN_{(VL)}$, $IN_{(WL)}$ - COM | -0.3 ~ $V_{DD} + 0.3$ | V |
| V_F | Fault Supply Voltage | Applied between V_F - COM | -0.3 ~ $V_{DD} + 0.3$ | V |
| I_F | Fault Current | Sink Current at V_F pin | 5 | mA |
| V_{SC} | Current Sensing Input Voltage | Applied between C_{SC} - COM | -0.3 ~ $V_{DD} + 0.3$ | V |

Total System

| Symbol | Parameter | Conditions | Rating | Unit |
|-----------------------|--|---|-----------|------------------|
| $V_{PN(\text{PROT})}$ | Self Protection Supply Voltage Limit (Short Circuit Protection Capability) | $V_{DD} = V_{BS} = 13.5 \sim 16.5 \text{ V}$ $T_J = 150^\circ\text{C}$, Non-Repetitive, $< 2 \mu\text{s}$ | 400 | V |
| T_{STG} | Storage Temperature | | -40 ~ 125 | $^\circ\text{C}$ |
| V_{ISO} | Isolation Voltage Connect Pins to Heat Sink Plate | AC 60 Hz, Sinusoidal, 1 Minute | 1500 | V_{rms} |

Thermal Resistance

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|----------------|-------------------------------------|---------------------------------------|------|------|------|-----------------------------|
| $R_{th(j-c)Q}$ | Junction to Case Thermal Resistance | Inverter IGBT part (per 1 / 6 module) | - | - | 5.9 | $^\circ\text{C} / \text{W}$ |
| $R_{th(j-c)F}$ | | Inverter FWD part (per 1 / 6 module) | - | - | 7.6 | $^\circ\text{C} / \text{W}$ |

Note:

6. For the measurement point of case temperature (T_C), please refer to Figure 2.

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified.)

Inverter Part

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit | | |
|---------------|--|--|--|--------------|------|------|----|----|
| $V_{CE(SAT)}$ | Collector - Emitter Saturation Voltage | $V_{DD} = V_{BS} = 15\text{ V}$ $V_{IN} = 5\text{ V}$ $I_C = 8\text{ A}$ | $T_J = 25^\circ\text{C}$ | - | 1.8 | 2.15 | V | |
| | | | $T_J = 150^\circ\text{C}$ | | 2.2 | | V | |
| V_F | FWDi Forward Voltage | $V_{IN} = 0\text{ V}$ $I_F = 8\text{ A}$ | $T_J = 25^\circ\text{C}$ | - | 2.0 | 2.4 | V | |
| | | | $T_J = 150^\circ\text{C}$ | | 1.8 | | V | |
| HS | t_{ON} | Switching Times | $V_{PN} = 400\text{ V}, V_{DD} = V_{BS} = 15\text{ V}, I_C = 10\text{ A}$ $T_J = 25^\circ\text{C}$ $V_{IN} = 0\text{ V} \leftrightarrow 5\text{ V}$, Inductive load (Note 7) | - | 700 | - | ns | |
| | | | | $t_{C(ON)}$ | - | 160 | - | ns |
| | | | | t_{OFF} | - | 700 | - | ns |
| | | | | $t_{C(OFF)}$ | - | 55 | - | ns |
| | | | | t_{rr} | - | 50 | - | ns |
| LS | t_{ON} | Switching Times | $V_{PN} = 400\text{ V}, V_{DD} = V_{BS} = 15\text{ V}, I_C = 10\text{ A}$ $T_J = 25^\circ\text{C}$ $V_{IN} = 0\text{ V} \leftrightarrow 5\text{ V}$, Inductive load (Note 7) | - | 700 | - | ns | |
| | | | | $t_{C(ON)}$ | - | 200 | - | ns |
| | | | | t_{OFF} | - | 750 | - | ns |
| | | | | $t_{C(OFF)}$ | - | 60 | - | ns |
| | | | | t_{rr} | - | 40 | - | ns |
| I_{CES} | Collector - Emitter Leakage Current | $V_{CE} = V_{CES}$ | - | - | 1 | mA | | |

Note:

7. t_{ON} and t_{OFF} include the propagation delay of the internal drive IC. $t_{C(ON)}$ and $t_{C(OFF)}$ are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Figure 4.

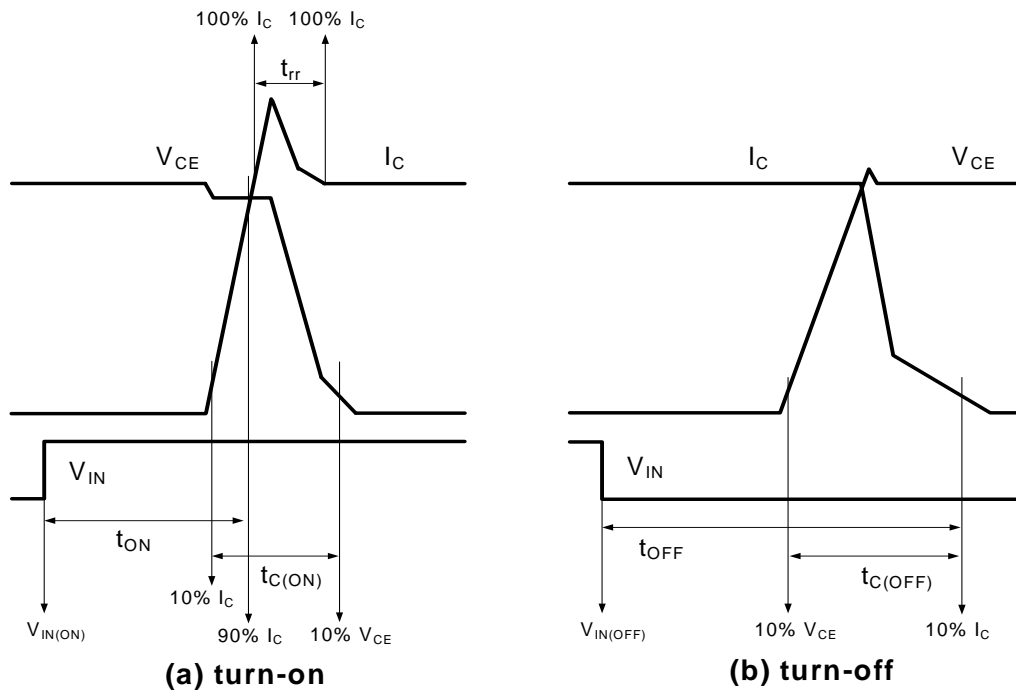


Figure 4. Switching Time Definition

Control Part

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit | |
|---------------|---|---|---|------|------|---------------|---------------|
| I_{QDD} | Quiescent V_{DD} Supply Current | $V_{DD} = 15\text{ V}$, $IN_{(UH, VH, WH, UL, VL, WL)} = 0\text{ V}$ | $V_{DD} - \text{COM}$ | - | 2.3 | 3.4 | mA |
| I_{PDD} | Operating V_{DD} Supply Current | $V_{DD} = 15\text{ V}$, $f_{PWM} = 20\text{ kHz}$, duty = 50%, applied to one PWM signal input | $V_{DD} - \text{COM}$ | - | 2.6 | 4.0 | mA |
| I_{QBS} | Quiescent V_{BS} Supply Current | $V_{BS} = 15\text{ V}$, $IN_{(UH, VH, WH)} = 0\text{ V}$ | $V_{B(U)} - V_{S(U)}$, $V_{B(V)} - V_{S(V)}$, $V_{B(W)} - V_{S(W)}$ | - | 60 | 100 | μA |
| I_{PBS} | Operating V_{BS} Supply Current | $V_{DD} = V_{BS} = 15\text{ V}$, $f_{PWM} = 20\text{ kHz}$, duty = 50%, applied to one PWM signal input for high - side | $V_{B(U)} - V_{S(U)}$, $V_{B(V)} - V_{S(V)}$, $V_{B(W)} - V_{S(W)}$ | - | 380 | 500 | μA |
| V_{FH} | Fault Output Voltage | $V_{SC} = 0\text{ V}$, V_F Circuit: 4.7 k Ω to 5 V Pull-up | 4.5 | - | - | V | |
| V_{FL} | | $V_{SC} = 1\text{ V}$, V_F Circuit: 4.7 k Ω to 5 V Pull-up | - | - | 0.5 | V | |
| $V_{SC(ref)}$ | Short-Circuit Trip Level | $V_{DD} = 15\text{ V}$ (Note 4) | 0.45 | 0.5 | 0.55 | V | |
| UV_{DDD} | Supply Circuit Under-Voltage Protection | Detection level | 10.0 | 11.5 | 13.0 | V | |
| UV_{DDR} | | Reset level | 10.5 | 12.0 | 13.5 | V | |
| UV_{BSD} | | Detection level | 9.5 | 11.0 | 12.5 | V | |
| UV_{BSR} | | Reset level | 10.0 | 11.5 | 13.0 | V | |
| I_{FT} | HVIC Temperature Sensing Current | $V_{DD} = V_{BS} = 15\text{ V}$, $T_{HVIC} = 25^\circ\text{C}$ | 70 | 95 | 120 | μA | |
| V_{FT} | HVIC Temperature Sensing Voltage | $V_{DD} = V_{BS} = 15\text{ V}$, $T_{HVIC} = 25^\circ\text{C}$, 4.7 k Ω to 5 V Pull-up (Figure. 5) | - | 4.55 | | V | |
| t_{FOD} | Fault-Out Pulse Width | | 40 | 100 | - | μs | |
| V_{FSDR} | Shut-down Reset level | Applied between $V_F - \text{COM}$ | - | - | 2.4 | V | |
| V_{FSDD} | Shut-down Detection level | | 0.8 | - | - | V | |
| $V_{IN(ON)}$ | ON Threshold Voltage | Applied between $IN_{(UH)}$, $IN_{(VH)}$, $IN_{(WH)}$, $IN_{(UL)}$, $IN_{(VL)}$, $IN_{(WL)} - \text{COM}$ | - | - | 2.4 | V | |
| $V_{IN(OFF)}$ | OFF Threshold Voltage | | 0.8 | - | - | V | |

Note:

8. Short-circuit protection is functioning for all six IGBTs.

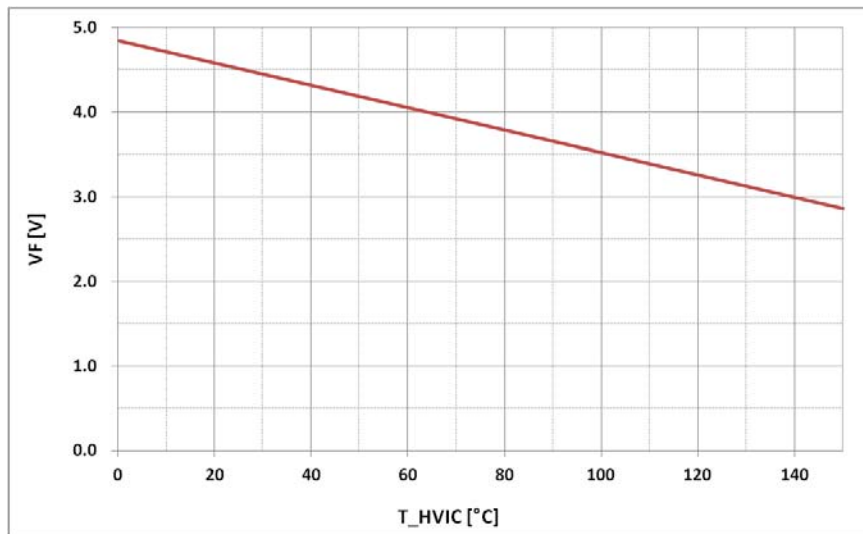


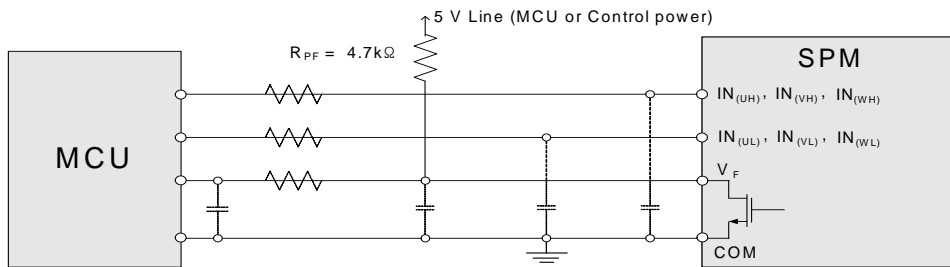
Figure. 5. V-T Curve of Temperature Output of IC (5V pull-up with 4.7kohm)

Recommended Operating Conditions

| Symbol | Parameter | Conditions | Min. | Typ. | Max. | Unit |
|--------------------------|--|---|------|------|------|-------------|
| V_{PN} | Supply Voltage | Applied between P - N_U, N_V, N_W | - | 300 | 400 | V |
| V_{DD} | Control Supply Voltage | Applied between V_{DD} - COM | 14.0 | 15 | 16.5 | V |
| V_{BS} | High - Side Bias Voltage | Applied between $V_{B(U)} - V_{S(U)}, V_{B(V)} - V_{S(V)}, V_{B(W)} - V_{S(W)}$ | 13.0 | 15 | 18.5 | V |
| $dV_{DD}/dt, dV_{BS}/dt$ | Control Supply Variation | | -1 | - | 1 | V / μ s |
| t_{dead} | Blanking Time for Preventing Arm - Short | For each input signal | 0.5 | - | - | μ s |
| f_{PWM} | PWM Input Signal | $-40^\circ\text{C} < T_J < 150^\circ\text{C}$ | - | - | 20 | kHz |
| V_{SEN} | Voltage for Current Sensing | Applied between N_U, N_V, N_W - COM (Including surge voltage) | -4 | | 4 | V |
| $P_{WIN(ON)}$ | Minimum Input Pulse Width | (Note 9) | 0.7 | - | - | μ s |
| $P_{WIN(OFF)}$ | | | 0.7 | - | - | |

Note:

9. This product might not make response if input pulse width is less than the recommended value.



Note:

10. RC coupling at each input (parts shown dotted) might change depending on the PWM control scheme used in the application and the wiring impedance of the application's printed circuit board. The input signal section of the SPM 55 product integrates 5 k Ω (typ.) pull-down resistor. Therefore, when using an external filtering resistor, please pay attention to the signal voltage drop at input terminal.

Figure 6. Recommended MCU I/O Interface Circuit

Mechanical Characteristics and Ratings

| Parameter | Conditions | Min. | Typ. | Max. | Unit | |
|-----------------|----------------------|-------------------------|------|------|------|---------|
| Device Flatness | See Figure 7 | -50 | - | 100 | μm | |
| Mounting Torque | Mounting Screw: - M3 | Recommended 0.7 N • m | 0.6 | 0.7 | 0.8 | N • m |
| | Note Figure 8 | Recommended 7.1 kg • cm | 5.9 | 6.9 | 7.9 | kg • cm |
| Weight | | - | 6.0 | - | g | |

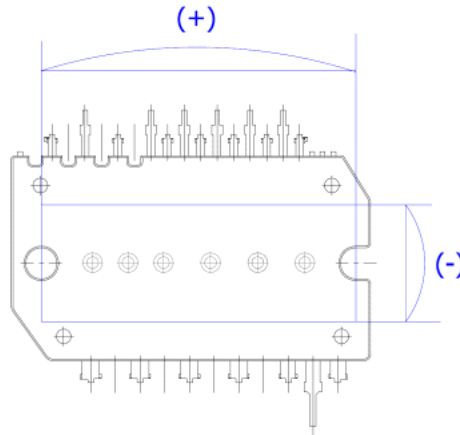


Figure 7. Flatness Measurement Position

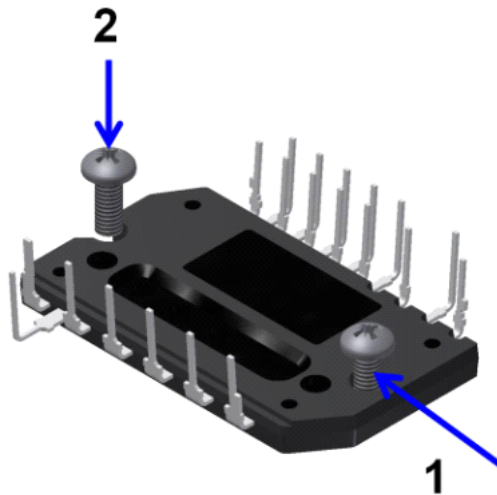
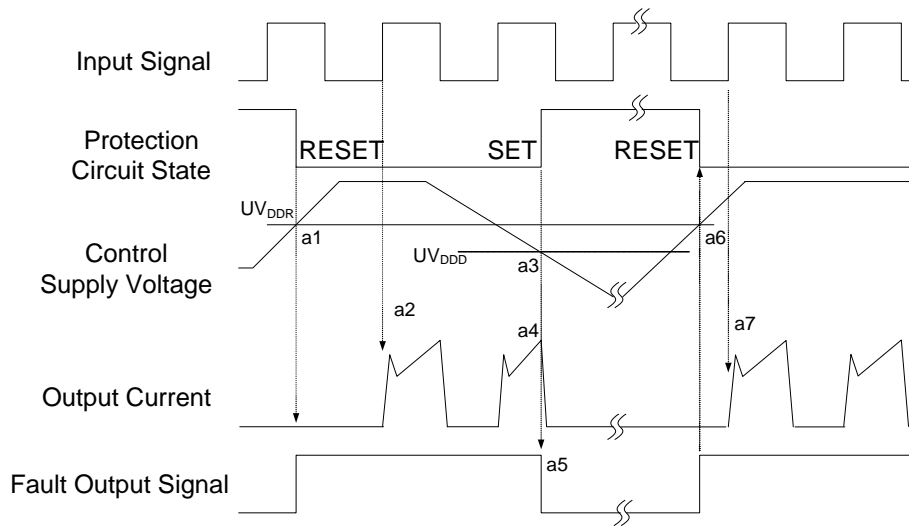


Figure 8. Mounting Screws Torque Order

Note:

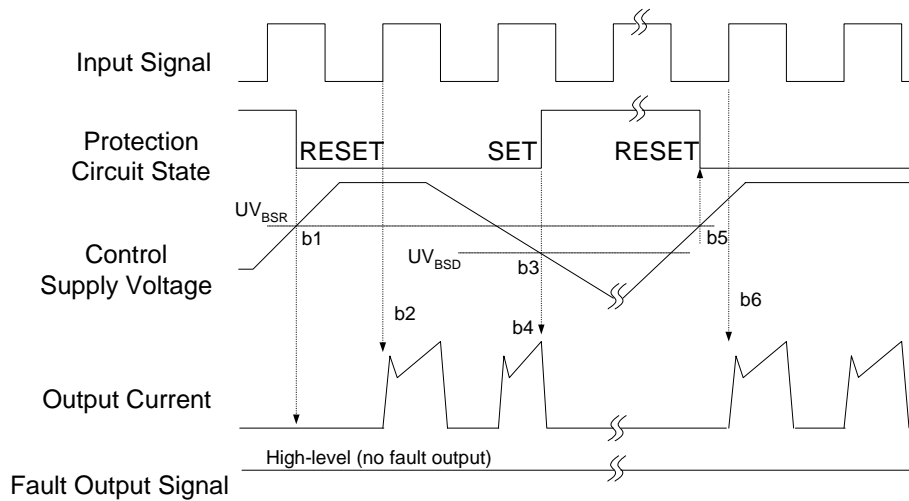
- 11. Do not make over torque when mounting screws. Much mounting torque may cause package cracks, as well as bolts and Al heat-sink destruction.
- 12. Avoid one side tightening stress. Figure 10 shows the recommended torque order for mounting screws. Uneven mounting can cause the ceramic substrate of the Motion SPM 55 product to be damaged. The Pre-screwing torque is set to 20 ~ 30 % of maximum torque rating.

Time Charts of Protective Function



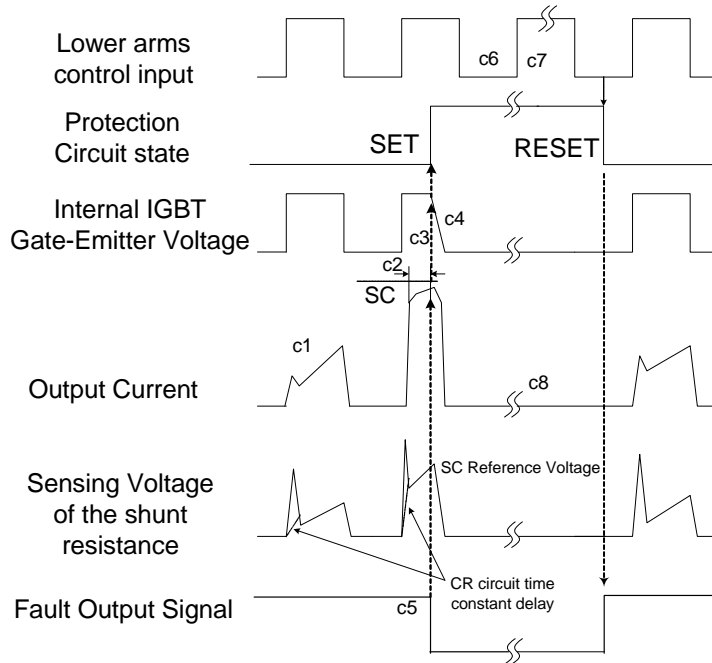
- a1 : Control supply voltage rises: After the voltage rises UV_{DDR} , the circuits start to operate when next input is applied.
- a2 : Normal operation: IGBT ON and carrying current.
- a3 : Under voltage detection ($UV_{DD\bar{D}}$).
- a4 : IGBT OFF in spite of control input condition.
- a5 : Fault output operation starts.
- a6 : Under voltage reset (UV_{DDR}).
- a7 : Normal operation: IGBT ON and carrying current.

Figure 9. Under-Voltage Protection (Low-Side)



- b1 : Control supply voltage rises: After the voltage reaches UV_{BSR} , the circuits start to operate when next input is applied.
- b2 : Normal operation: IGBT ON and carrying current.
- b3 : Under voltage detection ($UV_{BS\bar{D}}$).
- b4 : IGBT OFF in spite of control input condition, but there is no fault output signal.
- b5 : Under voltage reset (UV_{BSR})
- b6 : Normal operation: IGBT ON and carrying current

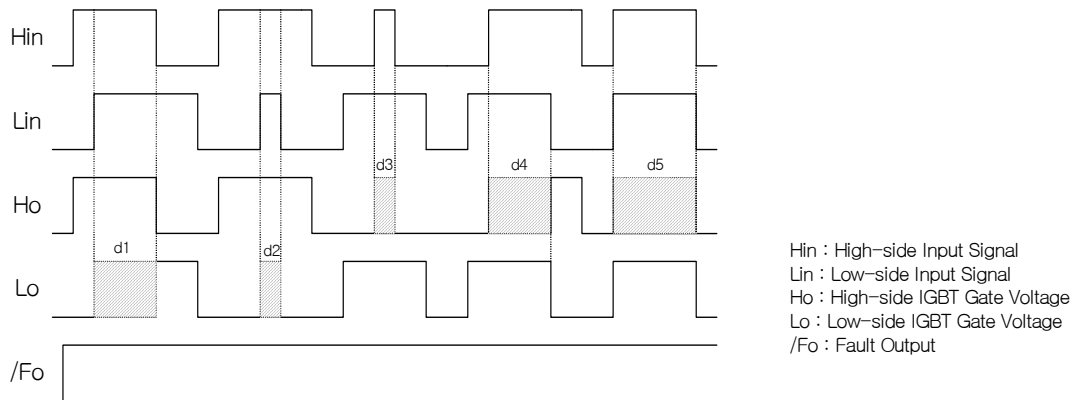
Figure 10. Under-Voltage Protection (High-Side)



(with the external shunt resistance and CR connection)

- c1 : Normal operation: IGBT ON and carrying current.
- c2 : Short circuit current detection (SC trigger).
- c3 : Hard IGBT gate interrupt.
- c4 : IGBT turns OFF.
- c5 : Input "L" : IGBT OFF state.
- c6 : Input "H" : IGBT ON state, but during the active period of fault output the IGBT doesn't turn ON.
- c7 : IGBT OFF state

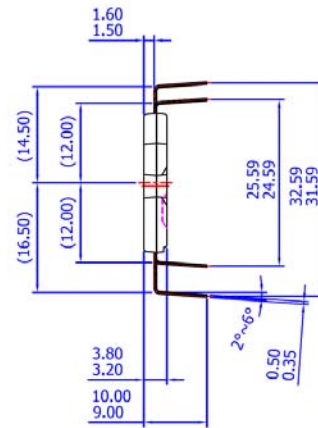
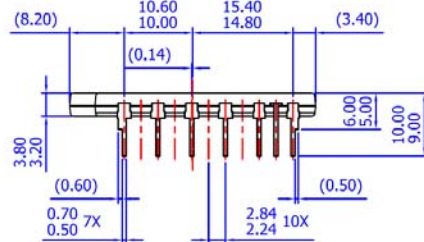
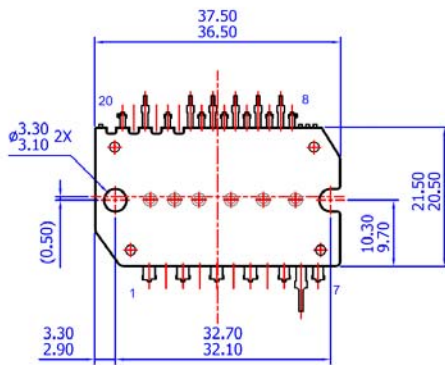
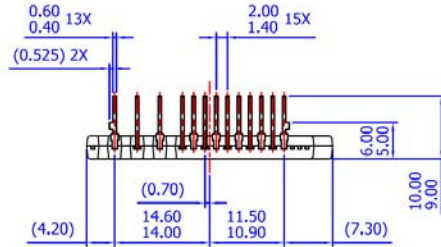
Figure 11. Short-Circuit Protection



- d1 : High Side First - Input - First - Output Mode
- d2 : Low Side Noise Mode : No Lo
- d3 : High Side Noise Mode : No Ho
- d4 : Low Side First - Input - First - Output Mode
- d5 : In - Phase Mode : No Ho

Figure 12. Inter-Lock Function

Detailed Package Outline Drawings (FNB51060T1, Short Lead)



- NOTES: UNLESS OTHERWISE SPECIFIED
- A) THIS PACKAGE DOES NOT COMPLY TO ANY CURRENT PACKAGING STANDARD
 - B) ALL DIMENSIONS ARE IN MILLIMETERS
 - C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
 - D) () IS REFERENCE
 - E) [] IS ASS'Y QUALITY
 - F) DRAWING FILENAME: MOD20DBREV2

ON Semiconductor and the ON Semiconductor logo are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada.
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: <http://www.onsemi.com/orderlit>

For additional information, please contact your local
Sales Representative

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that ON Semiconductor was negligent regarding the design or manufacture of the part. ON Semiconductor is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:



Literature Distribution Center for ON Semiconductor
19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA
Phone: 303-675-2175 or 800-344-3860 Toll Free USA/Canada
Fax: 303-675-2176 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada
Europe, Middle East and Africa Technical Support:
Phone: 421 33 790 2910
Japan Customer Focus Center
Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com
Order Literature: <http://www.onsemi.com/orderlit>
For additional information, please contact your local
Sales Representative

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

-  [View FNB51060T1 on WIN SOURCE](#)
-  [Fairchild/ON Semiconductor Information](#)

Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management